54F/74F189 64-Bit Random Access Memory with TRI-STATE® Outputs

General Description

The 'F189 is a high-speed 64-bit RAM organized as a 16-word by 4-bit array. Address inputs are buffered to minimize loading and are fully decoded on-chip. The outputs are TRI-STATE and are in the high impedance state whenever the Chip Select (CS) input is HIGH. The outputs are active only in the Read mode and the output data is the complement of the stored data.

Features

- TRI-STATE outputs for data bus applications
- Buffered inputs minimize loading
- Address decoding on-chip
- Diode clamped inputs minimize ringing
- Available in SOIC, (300 mil only)

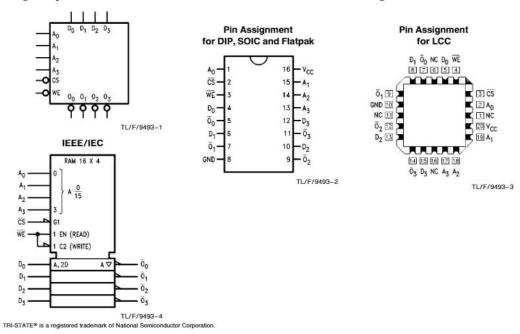
Commercial	Military	Package Number	Package Description
74F189PC		N16E	16-Lead (0.300" Wide) Molded Dual-In-Line
	54F189DL (Note 2)	J16A	16-Lead Ceramic Dual-In-Line
74F189SC (Note 1)		M16A	16-Lead (0.150" Wide) Molded Small Outline, JEDEC
74F189SJ (Note 1)		M16D	16-Lead (0.300" Wide) Molded Small Outline, EIAJ
	54F189FL (Note 2)	W16A	16-Lead Cerpack
	54F189LL (Note 2)	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C

Note 1: Devices also available in 13" reel. Use suffix = SCX and SJX.

Note 2: Military grade device with environmental and burn-in processing. Use suffix = DLQB, FLQB and LLQB.

Logic Symbols

Connection Diagrams



Unit Loading/Fan Out

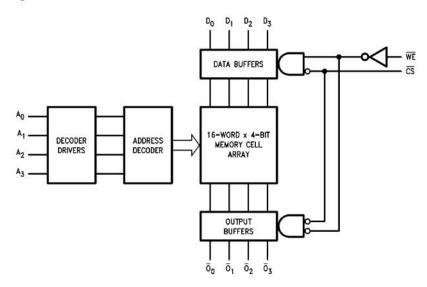
Pin Names		54F/74F				
	Description	U.L. HIGH/LOW	Input I _{IH} /I _{IL} Output I _{OH} /I _{OL}			
A ₀ -A ₃	Address Inputs	1.0/1.0	20 μA/ – 0.6 mA			
A ₀ -A ₃	Chip Select Input (Active LOW)	1.0/1.0	20 μA/ – 1.2 mA			
WE	Write Enable Input (Active LOW)	1.0/1.0	20 μA/ - 0.6 mA			
$\overline{O}_0 - \overline{O}_3$	Data Inputs Inverted Data Outputs	1.0/1.0 150/40 (33.3)	20 μA/ – 0.6 mA – 3.0 mA/24 mA (20 mA)			

Function Table

Inputs		Operation	Condition of Outputs				
CS WE		Орегацоп	Condition of Outputs				
E	L	Write	High Impedance				
L	Н	Read	Complement of Stored Data				
Н	X	Inhibit	High Impedance				

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Block Diagram



TL/F/9493-5

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

 $\begin{array}{lll} \text{Storage Temperature} & -65^{\circ}\text{C to} + 150^{\circ}\text{C} \\ \text{Ambient Temperature under Bias} & -55^{\circ}\text{C to} + 125^{\circ}\text{C} \\ \text{Junction Temperature under Bias} & -55^{\circ}\text{C to} + 175^{\circ}\text{C} \\ \text{Plastic} & -55^{\circ}\text{C to} + 150^{\circ}\text{C} \\ \end{array}$

V_{CC} Pin Potential to

 Ground Pin
 −0.5V to +7.0V

 Input Voltage (Note 2)
 −0.5V to +7.0V

 Input Current (Note 2)
 −30 mA to +5.0 mA

Voltage Applied to Output in HIGH State (with $V_{CC} = 0V$)

 $\begin{array}{lll} \text{Standard Output} & -0.5 \text{V to V}_{\text{CC}} \\ \text{TRI-STATE Output} & -0.5 \text{V to } +5.5 \text{V} \end{array}$

Current Applied to Output in LOW State (Max)

V State (Max) twice the rated I_{OL} (mA)

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature

Military −55°C to +125°C Commercial 0°C to +70°C

Supply Voltage

Military + 4.5V to + 5.5V Commercial + 4.5V to + 5.5V

DC Electrical Characteristics

Symbol	Parameter		54F/74F			Units	Vcc	Conditions	
Symbol			Min	Тур	Max	Offics	▼CC	Conditions	
V _{IH}			2.0			٧		Recognized as a HIGH Signa	
VIL	Input LOW Voltage				0.8	V		Recognized as a LOW Signal	
V _{CD}	Input Clamp Diode Voltage				-1.2	V	Min	$I_{\text{IN}} = -18 \text{mA}$	
V _{OH}	Output HIGH Voltage	54F 10% V _{CC} 54F 10% V _{CC} 74F 10% V _{CC} 74F 10% V _{CC} 74F 5% V _{CC} 74F 5% V _{CC}	2.5 2.4 2.5 2.4 2.7 2.7			v	Min	$I_{OH} = -1 \text{ mA}$ $I_{OH} = -3 \text{ mA}$ $I_{OH} = -1 \text{ mA}$ $I_{OH} = -3 \text{ mA}$ $I_{OH} = -1 \text{ mA}$ $I_{OH} = -3 \text{ mA}$	
V _{OL}	Output LOW Voltage	54F 10% V _{CC} 74F 10% V _{CC}			0.5 0.5	V	Min	$I_{OL} = 20 \text{ mA}$ $I_{OL} = 24 \text{ mA}$	
I _{IH}	Input HIGH Current	54F 74F			20.0 5.0	μΑ	Max	V _{IN} = 2.7V	
I _{BVI}	Input HIGH Current Breakdown Test	54F 74F			100 7.0	μΑ	Max	V _{IN} = 7.0V	
ICEX	Output HIGH Leakage Current	54F 74F			250 50	μΑ	Max	$v_{OUT} = v_{CC}$	
V _{ID}	Input Leakage Test	74F	4.75		*	٧	0.0	I _{ID} = 1.9 μA All Other Pins Grounded	
lop	Output Leakage Circuit Current	74F			3.75	μΑ	0.0	V _{IOD} = 150 mV All Other Pins Grounded	
I _{IL}	Input LOW Current				−0.6 −1.2	mA	Max	$V_{IN} = 0.5V \text{ (except } \overline{CS}\text{)}$ $V_{IN} = 0.5V \text{ (}\overline{CS}\text{)}$	
lozh	Output Leakage Curre	ent			50	μΑ	Max	V _{OUT} = 2.7V	
lozL	Output Leakage Current				-50	μΑ	Max	V _{OUT} = 0.5V	
los	Output Short-Circuit Current		-60		-150	mA	Max	V _{OUT} = 0V	
I _{ZZ}	Bus Drainage Test				500	μΑ	0.0V	V _{OUT} = 5.25V	
Iccz	Power Supply Curren	t		37	55	mA	Max	V _O = HIGH Z	

AC Electrical Characteristics

Symbol		$74F$ $T_{A} = +25^{\circ}C$ $V_{CC} = +5.0V$ $C_{L} = 50 \text{ pF}$			5	54F		74F	
	Parameter				*T _A , V _{CC} = Mil C _L = 50 pF		T _A , V _{CC} = Com C _L = 50 pF		Units
		Min	Тур	Max	Min	Max	Min	Max	
t _{PLH} t _{PHL}	Access Time, HIGH or LOW A_n to \overline{O}_n	10.0 8.0	18.5 13.5	26.0 19.0	9.0 8.0	32.0 23.0	10.0 8.0	27.0 20.0	ns
t _{PZH}	Access Time, HIGH or LOW CS to On	3.5 5.0	6.0 9.0	8.5 13.0	3.5 5.0	10.5 15.0	3.5 5.0	9.5 14.0	ns
t _{PHZ}	Disable Time, HIGH or LOW CS to On	2.0 3.0	4.0 5.5	6.0 8.0	2.0 2.5	8.0 10.0	2.0 3.0	7.0 9.0	ns
t _{PZH} t _{PZL}	Write Recovery Time, HIGH or LOW ₩E to On	6.5 6.5	15.0 11.0	28.0 15.5	6.5 6.5	37.5 17.5	6.5 6.5	29.0 16.5	ns
t _{PHZ}	Disable Time, HIGH or LOW WE to On	4.0 5.0	7.0 9.0	10.0 13.0	3.5 5.0	12.0 15.0	4.0 5.0	11.0 14.0	ns

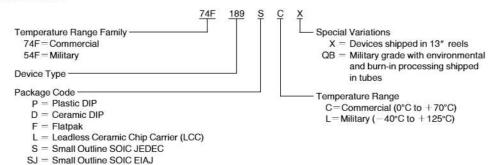
AC Operating Requirements

Symbol		74F T _A = +25°C V _{CC} = +5.0V		54	F	74F T _A , V _{CC} = Com		Units
	Parameter			*TA, VC	_C = Mil			
		Min	Max	Min	Max	Min	Max	
t _s (H) t _s (L)	Setup Time, HIGH or LOW A _n to WE	0		0		0		
t _h (H) t _h (L)	Hold Time, HIGH or LOW A _n to WE	2.0 2.0	12	2.0 2.0		2.0 2.0		ns
t _S (H) t _S (L)	Setup Time, HIGH or LOW D _n to WE	10.0 10.0		11.0 11.0		10.0 10.0		
t _h (H) t _h (L)	Hold Time, HIGH or LOW D _n to WE	0		2.0 2.0		0		ns
t _s (L)	Setup Time, LOW CS to WE	0		0		0		
t _h (L)	Hold Time, LOW CS to WE	6.0		7.5		6.0		ns
t _w (L)	WE Pulse Width, LOW	6.0		15.0		6.0		ns

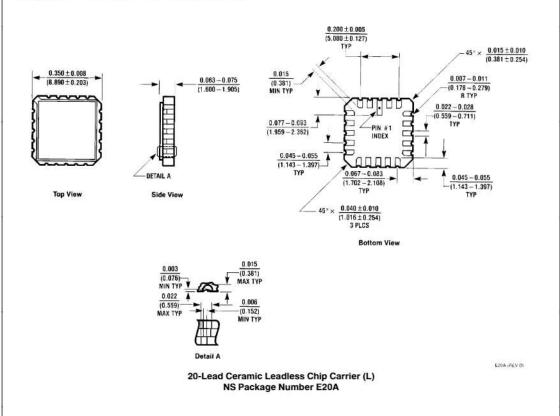
^{*}T_A = -55°C to +125°C

Ordering Information

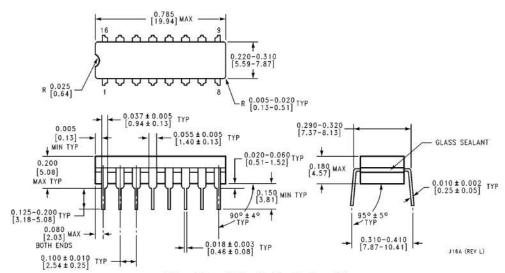
The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



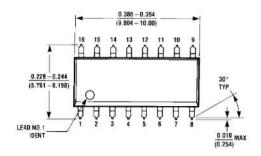
Physical Dimensions inches (millimeters)

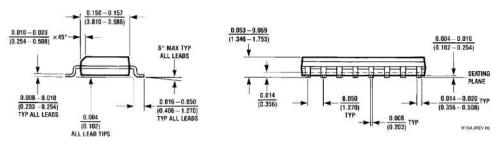


Physical Dimensions inches (millimeters) (Continued)

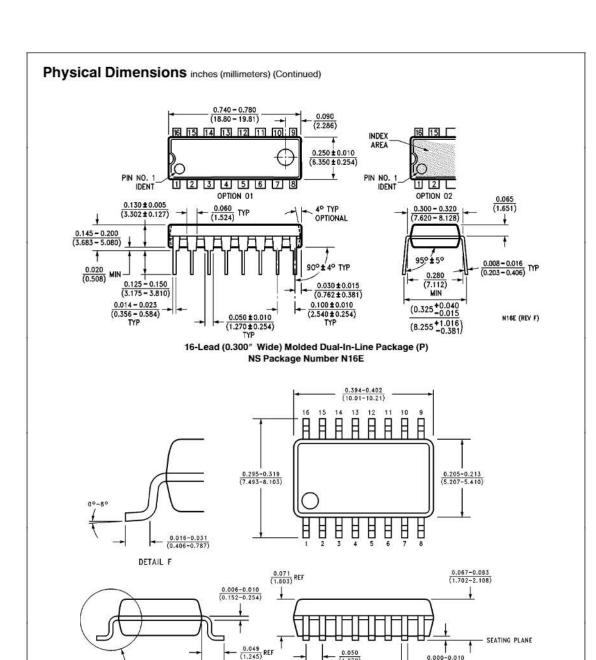


16-Lead Ceramic Dual-In-Line Package (D) NS Package Number J16A





16-Lead (0.150" Wide) Molded Small Outline Package, JEDEC (S)
NS Package Number M16A

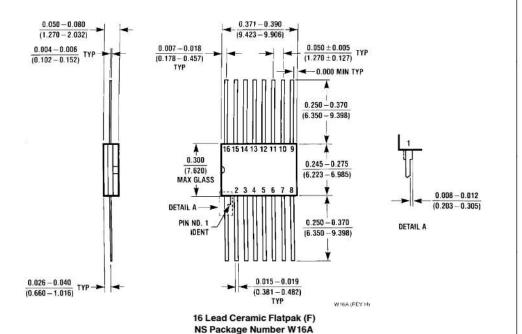


16-Lead (0.300" Wide) Molded Small Outline Package, EIAJ (SJ) NS Package Number M16D

M16D (REV A)

SEE DETAIL F

Physical Dimensions inches (millimeters) (Continued)



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